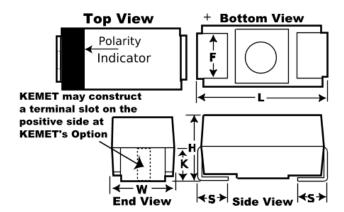


T495T336M006ZTE800

Obsolete

 $Tantalum, MnO2\ Tantalum, 33\ uF, 20\%, 6.3\ VDC, SMD, Molded, Low Profile, Low ESR, Surge Robust, 800\ mOhms, 3528, 1.2mm$



Dimensions		
Footprint	3528	_
L	3.5mm +/-0.2mm	
W	2.8mm +/-0.2mm	
Н	1.2mm MAX	
S	0.8mm +/-0.3mm	
F	2.2mm +/-0.1mm	
K	1mm TYP	

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2500

General Information		
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, Molded, Low Profile, Low ESR, Surge Robust	
Features	Low Profile, Low ESR, Surge Robust	
RoHS	Yes	
Termination	Tin	
AEC-Q200	No	
Notes	Obsolete. Old Part Number [Obsolete] Was B45190R1336M209.	

Specifications	
Capacitance	33 uF
Capacitance Tolerance	20%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.8 Ohms (100kHz)
Ripple Current	310 mAmps (25C), 279 mAmps (85C), 124 mAmps (125C)
Leakage Current	2.1 uA

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